

**(Tl, Au)/Si(111) and (Tl, Au)/Si(100) 2D compounds:  
Atomic and electronic structure and transport properties**

A.N. Mihalyuk<sup>1,2</sup>, C.R. Hsing<sup>3</sup>, C.M. Wei<sup>3</sup>, S.V. Ereemeev<sup>4,5</sup>, A.V. Matetskiy<sup>1</sup>, N.V. Denisov<sup>1</sup>,  
L.V. Bondarenko<sup>1</sup>, A.Y. Tupchaya<sup>1</sup>, D.V. Gruznev<sup>1</sup>, A.V. Zotov<sup>1,2,6</sup>, A.A. Saranin<sup>1,2</sup>

<sup>1</sup>*Institute of Automation and Control Processes FEB RAS, 5 Radio Street, 690041 Vladivostok, Russia*

<sup>2</sup>*School of Natural Sciences, Far Eastern Federal University, 690950 Vladivostok, Russia*

*e-mail: saranin@iacp.dvo.ru*

<sup>3</sup>*Institute of Atomic and Molecular Sciences, Academia Sinica, P.O. Box 23-166 Taipei, Taiwan*

<sup>4</sup>*Institute of Strength Physics and Materials Science SB RAS, 634021 Tomsk, Russia*

<sup>5</sup>*Tomsk State University, 634050 Tomsk, Russia*

<sup>6</sup>*Department of Electronics, Vladivostok State University of Economics and Service, 690600 Vladivostok, Russia*

Discovery of graphene has stimulated the current interest to atomically thin, two-dimensional (2D) materials which might exhibit unique properties not observed in the bulk materials. Metal-induced surface reconstructions on silicon and germanium (i.e., metal films of a monolayer or submonolayer thickness on silicon or germanium) are vivid examples. Most of the studies in this field have been restricted to reconstructions built of a single atomic species. Natural expansion of the research area is the exploration of the 2D multi-component systems.

Formation of the highly-ordered  $\sqrt{7}\times\sqrt{7}$ -periodicity 2D compound has been detected in the (Tl, Au)/Si(111) system as a result of Au deposition onto the Tl/Si(111) surface and its composition, structure and electronic properties have been characterized using scanning tunneling microscopy (STM), angle-resolved photoelectron spectroscopy (ARPES) observations and density-functional-theory (DFT) calculations. On the basis of these data, the structural model of the Tl-Au compound has been proposed, which adopts 12 Tl atoms and 10 Au atoms (in total, 22 atoms) per  $\sqrt{7}\times\sqrt{7}$  unit cell, i.e.  $\sim 1.71$  ML of Tl and  $\sim 1.43$  ML of Au (in total,  $\sim 3.14$  ML). Qualitatively, the model can be visualized as consisting of truncated-pyramid-like Au clusters with a Tl atom on top, while the other Tl atoms form a double layer around the Au clusters.

On the Si(100) formation of the highly-ordered  $\sqrt{2}\times\sqrt{2}$ -periodicity 2D compound has been detected and its composition, structure and electronic properties have been characterized using STM, ARPES spectroscopy observations and DFT calculations. The structural model of this Tl-Au compound on the Si(100) surface is much simpler than that on the Si(111) one. It adopts 2 Tl atoms and 2 Au atoms per  $\sqrt{2}\times\sqrt{2}$  unit cell, i.e. 1.0 ML of Tl and 1.0 ML of Au (in total, 2.0 ML).

Both (Tl, Au)/Si(111) $\sqrt{7}\times\sqrt{7}$  and (Tl, Au)/Si(100) $\sqrt{2}\times\sqrt{2}$  compound has been found to exhibit pronounced metallic properties at least down to the temperatures as low as  $\sim 2$  K. Low-temperature magnetotransport properties will be discussed in the talk.